Attorney's Docket No.: 16459-013001



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Splicant: Alexei A. Erchak

Art Unit: 2811

Serial No.: 10/735,498

Examiner: Unknown

Filed

: December 12, 2003

Title

: LIGHT EMITTING SYSTEMS

Mail Stop Amendment

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Applicants submit the references listed on the attached form PTO-1449. Applicants also bring to the Examiner's attention the below listed 14 pending U.S. utility patent applications that are owned by the Assignee of the above-noted patent application.

Document Number	Patentee	Filing Date
10/724,004	Alexei A. Erchak et al	11/26/03
10/723,987	Alexei A. Erchak	11/26/03
10/724,033	Alexei A. Erchak	11/26/03
10/724,006	Alexei A. Erchak	11/26/03
10/724,029	Alexei A. Erchak	11/26/03
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10/724,005	Alexei A. Erchak	11/26/03
10/794,244	Alexei A. Erchak	3/5/04
10/794,452	Alexei A. Erchak	3/5/04
10/872,335	Alexei A. Erchak et al.	6/18/04
10/896,606	Alexei A. Erchak et al.	7/22/04
10/871,877	Alexei A. Erchak et al	6/18/04
10/872,336	Alexei A. Erchak et al.	6/18/04
10/896,435	Alexei A. Erchak et al.	7/22/04

CERTIFICATE OF MAILING BY FIRST CLASS MAIL

I hereby certify under 37 CFR §1.8(a) that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage on the date indicated below and is addressed to the Commissioner for Patents, P₁O. Box 1450, Alexandria, VA 22313-1450.

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Applicant: Alexei A. Erchak Attorney's Docket No.: 16459-013001

Serial No.: 10/735,498

Filed: December 12, 2003

Page : 2 of 2

This statement is being filed within three months of the filing date of the application or before the receipt of a first Office Action on the merits. Please apply any charges or credits to Deposit Account No. 06-1050.

Respectfully submitted,

Date: 10 15 for

Sean P. Daley Reg. No. 40,978

Fish & Richardson P.C. 225 Franklin Street Boston, MA 02110-2804 Telephone: (617) 542-5070 Facsimile: (617) 542-8906

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Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office		Application No. 10/735,498
Information Disc by Ap	closure Statement	Applicant Alexei A. Erchak	
	eets if necessar() 007 1 8 2004	Fling Date December 12, 2003	Group Art Unit 2811

	U.S. Parent Documents						
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
	AA	5,359,345	10/25/94	Hunter et al.			
	AB	5,631,190	05/20/97	Negley et al.			
	AC	5,724,062	03/03/98	Hunter et al.			
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	Foreign Patent Documents or Published Foreign Patent Applications							
Examiner	Desig.	Document	Publication	Country or			Trans	lation
Initial	ID	Number	Date	Patent Office	Class	Subclass	Yes	No
	AT	WO 98/14986	04/09/98	PCT				

Other Documents (include Author, Title, Date, and Place of Publication)		
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	AU	W.S. Wong et al. "Damage-free separation of GaN thin films from sapphire substrates", Appl. Phys. Lett. 72 (5), February 2, 1998, pages 599-601

Examiner Signature	Date Considered
EXAMINER: Initials citation considered. Draw line through citation if no next communication to applicant.	t in conformance and not considered. Include copy of this form with

Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Traceman Office	Attorney's Docket No. 16459-013001	Application No. 10/735,498
	plicant	Applicant Alexei A. Erchak	
(Use several sh	eets if necessary)	Filing Date December 12, 2003	Group Art Unit 2811
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•	Other Documents (include Author, Title, Date, and Place of Publication)				
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	AV	M.K. Kelly et al. "Optical process for liftoff of Group III-nitride films", Physica Status Solidi; Rapid Research Note, November 28, 1996, 2 pages.			
	AW	A. A. Erchak et al. "Enhanced coupling to vertical radiation using a two-dimensional photonic crystal in a semiconductor light-emitting diode", Appl. Phys. Lett. (78 (5), January 29, 2001, pages 563-565			
	AX	P.L. Gourley et al. "Optical properties of two-dimensional photonic lattices fabricated as honeycomb nanostructures in compound semiconductors", Appl. Phys. Lett. 64(6), February 7, 1994, pages 687-689			
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	ANN	M.K. Kelly et al. "Optical patterning of GaN films", Appl. Phys. Lett 68 (12), September 16, 1996, pages 1749-1751			

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